

Project Report

Comprehensive analysis of electronic noise and their noise spectra of zener diode

MSc Semester 3 Unit 505: Project Work

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Abstract

This is our semester project in which we studied noise from source zener diode specifically BZX55C5V1. We looked for low frequency flicker noise, johnson noise and shot noise traces. In this project we used a lock-in amplifier specifically SR830 which is relatively accurate and low noise. We used the relative capability of SR830 that of minimum detection around 10nV/Hz signal. We made open source community with making python library pyinstro for controlling and interfacing instruments like SR830. This program is made to be very flexible and highly extensible for use in every SCPI supported interface like GPIB, RS232, USB, LAN with capabilities like built-in file writer (.csv) and some CLI argument parsing.

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1 Introduction

Regulated power sources are extremely important in day to day lab work. Zener diodes and passive elements share an integral part of the overall circuit of regulated power supply. When we are dealing with precision measurement and study we need the most precise power sources to work with but because of 'Noise' of components of zener diodes and passive elements it inherits noise internally. Since, this noise will be infested in precision work we are doing in the lab. It is better to study the known structure of noise in these devices to address methodic treatment to our data and circuits. With all this in mind we are doing noise measurement and studying the noise spectrum of the zener diode.

For this semester we had radical plans to try but it evolved into more mature or downgraded in a way. First tried as shot noise to generate a random number generator which could possibly be a true random generator with little transformations. Then we eyed the more on general idea of studying noise theoretically and doing analysis experimentally. Which is exactly what we are doing right now but change is that at start we are working with photodiode and now with zener diode. Thanks to Dr. U S Joshi sir who guided us to try different diodes against photodiode. In this report we are having the following parts in order. First we are studying theoretically components, then we will discuss methods and tools that we used included all instrumentation, data acquisition, data analysis etc., we will conclude with our results and discuss it. The foundational work in thermal noise was done by J B johnson in his paper [site it].

2 Theoretical compilation

This section will deal with theoretical components from our project. Here, linear circuit analysis gives noise and output voltage relationship.

2.1 Linear circuit analysis

We have a voltage regulator circuit from a zener diode which regulates voltages at specific voltage known as zener voltage V_z . The fluctuation from these regulated voltages is what we call noise. Since ideal regulators only give pure DC voltages at output, this fluctuation is completely unwanted and only be resultant of intrinsic noise of this regulator circuit. We limit ourselves with only noise coming from zener diode which is not quite good practice. Since, noise can be added from extra resistors, wires and even the power supply itself. The resistor noise can be neglected because of their low values as we used 10k in series and 100k in parallel to output. We will see this later.

Let's take a basic voltage regulator circuit as shown in figure 1.

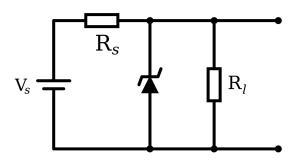


Figure 1: Simple voltage regulator circuit made from zener diode

As you can see we have a zener diode parallel to the power supply, which regulates at a certain degree. Since this is a linear circuit output voltage can be easily derived.

Applying kirchhoff current low in the figure 1,

$$\begin{split} I_z &= I_{R_s} - I_L \\ &= \frac{V_s - V_o}{R_s} - \frac{V_o}{R_L} \\ &= -V_o(\frac{1}{R_s} + \frac{1}{R_L}) + \frac{V_s}{R_s} \\ &= -V_o A' + B' \end{split}$$

Here,
$$A' = (\frac{1}{R_s} + \frac{1}{R_L})$$
 and $B' = \frac{V_s}{R_s}$.

We can write $I_z = \frac{V_z}{R_z}$, where V_z and R_z are respectively zener voltages and impedance. This relation is quite linear in the breakdown region as you can see in the figure 2. ¹

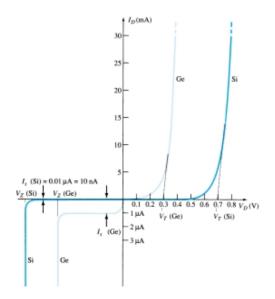


Figure 2: theoretical current and voltage relation for zener diode

Here we can assume equivalent circuit of ?? as figure ??

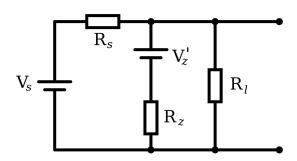


Figure 3: Equivalent circuit of figure 1

Further, simplifying the circuit,

This circuit is further simplified as we take $V_z = V_{DC} + V_n$ where V_n is the noise voltage of the zener diode. If we neglect noise from other sources like resistors and power supply then from figure 4,

¹Image is taken from Electronics Devices and Circuit Theory by Robert Boylsted

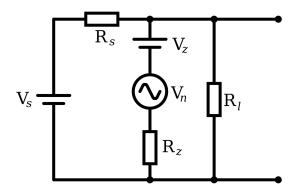


Figure 4: Equivalent circuit of figure 3

$$\frac{V_z}{I_z} = -V_o A' + B'$$

$$\frac{V_{DC} + V_n}{I_z} = -V_o A' + B'$$

$$V_n = -V_o A + B$$

$$V_o = -\frac{V_n}{A} + \frac{B}{A} \tag{1}$$

So, we can conclude that here as V_oV_n . This will be the main focus of this project. Here we are neglecting V_{DC} and will be totally okay when we read data from the LOCK IN amplifier, since the DC component has zero frequency which can't be read from the LOCK IN amplifier.

2.2 Different noises in the circuit

The noise voltage V_n is made from different types of noise source which can act as a symbol voltage source. So, V_n can be broken into sub noise sources such as $V_n = V_{flicker} + V_{thermal} + V_{shot} + \cdots$. We will see this noise source and its origin then we will derive its respective distribution and equations.

2.2.1 Flicker Noise

Flicker noise is also known as 1/f noise in view of the fact that power density decreases with increasing frequency. This implies that at lower frequencies, the flicker noise dominates.

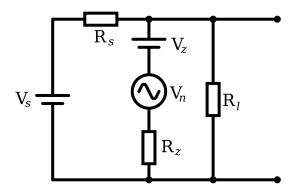


Figure 5: Equivalent noise sources 3

This type of noise is found almost in any electronic device which is able to operate at lower frequencies. The main source of this type of noise is D.C supply. Its first evidence was given by J. B. Johnson [?]. Its first 1/f form is derived by beck and spruit [?]. Now the form is given as

$$S(f) = \frac{C}{f^{\alpha}} \tag{2}$$

Here, C and α determine the nature of flicker noise. $\alpha determine relations with other noise elements$

- 1. $(\alpha > 0)$: This means that white noise is dominating the flicker noise as frequency increases.
- 2. $(\alpha = 0)$: This means that only white noise is exists
- 3. $(\alpha < 0)$: This means noise is increasing as frequency. Also, shows that noise will be persistent with a higher range of frequencies. Typically white noise dominates traditional flicker noise.

We can see noise levels as from figure ??.

2.2.2 Shot noise

Shot noise is a form of noise that arises because of the discrete nature of the charges carried by charge carriers, electrons or holes or photons hitting the surface. Shot noise is analogous to the rainfall in which raindrop hitting the surface can be considered as discrete. The sound of rainfall is very similar to noise we hear from speakers when we are considering shot noise.

Since, shot noise is a phenomenon for discrete charge passing through a junction, it can be modelled by poisson distribution. Suppose that In the time interval the τ Q charge

passes through a junction in a semiconductor device (in present context zener diode). This gives rise to discrete probability distribution,

$$P(N) = \frac{e^{-\lambda \tau} (\lambda \tau)^N}{N!} \tag{3}$$

If N=0 charge passes in time interval τ then P(N) will be,

$$P(0) = e^{-\lambda \tau} \tag{4}$$

Now suppose, probability of one and only one charge passing through junction in time

$$P(\tau)d\tau = (P_{\tau}(0))(P_{\tau}(1))$$

From equation ??,

 τ ,

$$P(\tau)d\tau = (e^{-I_0\tau})(e^{-I_0d\tau}I_0d\tau)$$

$$P(\tau) = (e^{-I_0(\tau + d\tau)})I_0$$

We can write this equation in frequency domain and by,

$$P(f) = Sdf (5)$$

Where S is the spectral density of noise.

Here we can write specific form for shot noise in equation ?? [?].

$$\langle V_{shot}^2 \rangle = 2eI_0 df \tag{6}$$

Here, e is electron charge,

 I_0 is average current,

df is ENBW = Equivalent Noise Bandwidth

$$S(f) = 2eI_0 \tag{7}$$

This spectral density gives independence to frequency, which is called white noise.

[Graphs]

2.2.3 Avalanche or zener noise

avalanche noise often considers the device's operating characteristics in the avalanche breakdown region. It is a major problem where the device is working in avalanche breakdown regions. It is multiplicative noise where chains of electrons crossing from junction rise to noise behaviour. It is very similar to shot noise and we can use that model and just use a multiplicative element in it. In our circuit this is significant since we are dealing with zener diode. With potential gradient inside the zener diode, if any hole and electron pair generates, it gets dragged by potential and hits the other lattice. This creates chain reaction and very high amplitude noise measured.

$$\langle V_{avalanche}^2 \rangle = M V_{shot}^2 \rangle$$

$$\langle V_{avalanche}^2 \rangle = 2eMI_0 df$$
 (8)

So, the spectral density S(f) of this noise will be nearly white.

Here, we can combine this both avalanche and shot noise to make one noise source, beginalign* $_{s}^{2}\rangle =_{shot}^{2}\rangle +_{avalanche}^{2}\rangle = 2eI_{0}df + 2eMI_{0}df = (M+1)2eI_{0}df$

And spectral density will be $S(f) = (M+1)2eI_0$

Since this noise is white noise we can measure at every frequency. This is what we are going to do in the next chapter.

2.2.4 Thermal noise

Thermal noise, also called Johnson–Nyquist noise is the electronic noise generated by random motion of charge carriers. This charge carrier is generated by the thermal agitation inside an electrical conductor at equilibrium, which happens regardless of any applied voltage. Because of their random motion it can be said that they have a mean value at zero. This reason says that we can't model this noise by poisson distribution but have to model with normal or gaussian distribution. In 1936, J B Johnson first gave an idea about thermal noise in thermionic valves. [?]

The noise amplitude is very similar to that of shot noise and given as,

$$\langle V_s hot^2 \rangle = 4K_B R df \tag{9}$$

Here, K_B is boltzmann constant,

R is resistance of device or component, df is ENBW.

$$S(f) = 4K_B R \tag{10}$$

By equation 10 we can see that thermal noise in an ideal resistor is approximately white, meaning that the power spectral density is nearly constant throughout the frequency spectrum. But practically it does decay to zero at extremely high frequencies (terahertz for room temperature). Also, we are neglecting quantum effects.

Total noise in the circuit

3 Methodology

3.1 Our voltage regulation circuit

Our purpose was to regulate voltages and also study noise related to the circuit. If we choose a complicated circuit for voltage voltage regulation then analysis of noise will be relatively complicated. So, we used a very basic voltage regulator circuit from a zener diode. Supply was given as DC power supply with voltage V_s . This voltage is decided by the zener voltage at hand.

The noise in the circuit will be relatively higher at the zener breakdown region. As we discussed from the theoretical part, noise power will be proportional to current flowing in the zener diode (here, we are assuming that noise from other parts is almost zero). To prepare a zener diode (BZX55C5V1) to break down the region we choose 5.4V. This is calculated from For our purpose we utilised a general purpose zener diode with breakdown region between 4.8V to 5.4V with current of μA order. We first did the Current and voltage characteristics of zener diodes. The useful information we got from there is source voltages, zener voltages and current that we particularly needed in our project. Our aim was to never exceed the LOCK IN amplifier's input limits. Current and voltage characteristics are down in figure 7. The zener diode we used had its datasheets, which you can see from Appendix. Its power rating is ...



Figure 6: Our zener diode

The zener diode was given proper voltages to work in reverse bias, specifically in the breakdown region. The overall circuit was identical to that of voltage regulator by zener diode. We gave particularly 5.0 V, 5.5V in two different runs from the powersource. The Zener diode regulated around 4.9 V.

Now, what we need is that fluctuation over the regulated DC voltage. These fluctuations have to be some function in the frequency domain as we assumed. This function must be made of different harmonics of sinusoidal waves with different phases and frequencies as thought by Fourier and his analysis. So basically we needed a system to measure different amplitudes of these harmonics at different frequencies to model our fluctuations. We needed a complete frequency spectrum at the particular bandwidth we are looking for in this analysis. The LOCK IN amplifier gives exactly that.

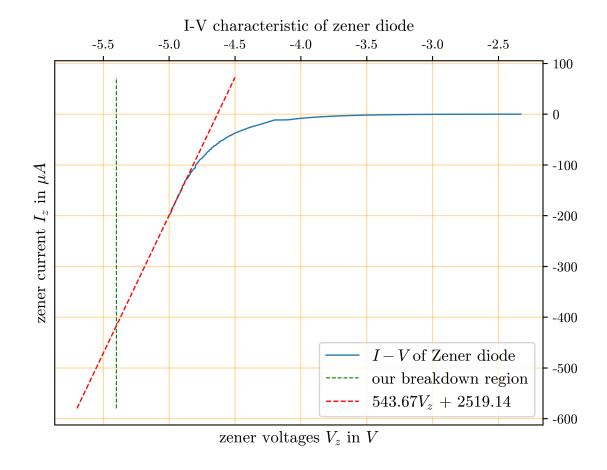


Figure 7: current and voltage characterists of zener diode

3.2 Measuring instrument: LOCK IN amplifier

LOCK IN amplifiers came in the 1930s and became very important in signal extraction from given frequency and phase. It is very helpful in measuring signals in a very noisy environment. It takes two inputs, one which is being measured and one which is given as a reference mono frequency signal. Reference signal gets multiplied with input signal and gives output through a process called Phase sensitive detection in which it uses homodyne detection scheme and filters out signal as DC component. We will see in a bit.

3.2.1 Phase sensitive detection

In nutshell it uses frequency multiplication and generates double side bands which then pass through a low pass filter to extract signal. In figure ?? you can see a signal first goes into a low noise differential amplifier which strengthens the signal. Signal Gets multiplied by another reference signal. This gives rise to two bands which pass through a low pass filter which cancels higher degree signal and only left is low frequency signal.

If we take signal $V_s(t)$ with frequency w_s , amplitude A and phase θ .

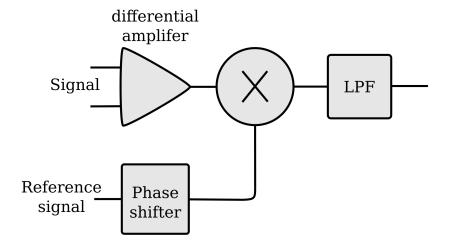


Figure 8: basic phase sensitive detector

$$V_s(t) = A\cos(w_s t + \theta)$$
$$= \frac{A}{2} (e^{i(w_s t + \theta)} + e^{-i(w_s t + \theta)})$$

Reference signal can be taken as following,

$$V_r(t) = B(e^{-i(w_r t + \phi)})$$

In common settings, $\phi = 0$ and B = 1,

$$V_r(t) = e^{i(-w_r t)}$$

Together after mixing the signals we have,

$$Z(t) = V_s(t)_r(t)$$

$$= \frac{A}{2} \left(e^{i[(w_s - w_r)t + \theta]} + e^{-i[(w_s + w_r)t + \theta]} \right)$$

$$= X(t) + Y(t)$$

Making $w_s = w_r$ which makes subtraction vanishes and only one term with higher frequency lefts. Passing this signal through a low pass filter with very low cutoff gives only DC components and rejects noise even from neighbouring frequencies.

$$Z(t) = \frac{A}{2}(e^{i\theta})$$

Two component X(t) and Y(t) becomes,

$$X(t) = Re(Z(t))$$

$$= \frac{A}{2}\cos(\theta)$$

And,

$$Y(t) = Im(Z(t))$$

$$= \frac{A}{2}\sin(\theta)$$

So, Amplitude and Phase becomes,

$$R = \sqrt{X(t)^2 + Y(t)^2}$$

$$= \sqrt{(\frac{A}{2}\cos(\theta))^2 + (\frac{A}{2}\sin(\theta))^2}$$

$$\Theta = \arctan(\frac{Y}{X})$$

So, the final product in PSD is the absolute amplitude of the signal and its phase.

- 3.2.2 Time Constant
- 3.2.3 ENBW
- 3.2.4 Sensitivity

3.2.5 LOCK IN amplifier over traditional measuring device/system

For noise analysis LOCK IN amplifiers are the optimal choice. Traditional approaches deal with the first measurement of a small signal in the time domain. This signal gets am-

plified with additional noise from the amplifier. Also, amplifiers attenuates signals with its limited bandwidth which is a measure of concern for certain use case scenarios. This attenuated signal gets into some detector. For signal analysis, this signal must go into other processes like analog to digital conversion then Fourier transformation. This whole process gives too much concerned noise which is not related to devices being analysed in our case the voltage regulator circuit. Alternative approach is to go with a LOCK IN amplifier. Which cancels out most burdens of traditional measurement steps. This whole combined help in reducing internal noise and increasing S/N ratio.

Pros of LOCK IN amplifier:

- LOCK In amplifiers reduces attenuation of signal with increasing frequency since it does not measure signal in the whole frequency spectrum.
- Increase S/N ratio over traditional amplifier circuit
- Gives direct data into frequency domain

Cons of LOCK IN amplifier:

- Relatively expensive
- Does not give information in time domain
- Relatively slow for whole analysis of frequency domain (low but accurate resolution of frequency domain)

3.3 SR830

We used a LOCK IN amplifier from Stanford Research Systems. It is used to detect low amplitude signals as low as $10\frac{nV}{Hz}$ and frequency as low as 100mV. and measure very small AC signals - upto few nanovolts. Accurate measurements may be made even when the small signal is obscured by noise sources many thousands of times larger.

3.3.1 Internal structure of SR830

3.3.2 Inputs

3.3.3 Outputs

3.3.4 Interfacing

Lock-in amplifiers use a technique known as phase-sensitive detection to single out the component of the signal at a specific reference frequency and phase. Noise signals at frequencies other than the reference frequency are rejected and do not affect the measurements.

Now, on the basis of frequencies/ frequency levels and its origin, there are different types of noises are present in our environment. Some of them are discussed below:

4 Analysis and Results

We have surveyed voltage regulated circuits we made with zener diodes and found some satisfactory results. We take different results for different bandwidths. For context this is row data from different bandwidth. Here, for each set of frequencies in bandwidth we took almost 50 to 100 readings.

4.1 Low frequency: upto 10k

We are mainly focused low frequency results since we are only intrested in regulated power supply applications. We had original assumption that in low frequency flicker noise is higly dominating.

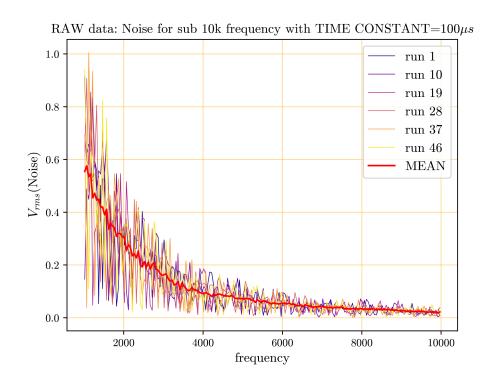


Figure 9: This is row data for 1k to 10k frequency band TIME CONSTANT = $100\mu s$ and 12db/oct

Here initial results were quite random, which means we have to filter our data a bit. For this reason we used a basic filtering method. In this method the data are sorted out as minimum deviation from their minimum then we took the upper 5 to 10 results and took the mean of it. The basic implementation is as following,

Let, X(f) as data point for specific f and Y(f) be sorted data with n number of

results,

$$\langle X(f) \rangle = \sum_{i=0}^{N-1} X^{(i)}(f)$$

$$Y_n(f) = \max(t \operatorname{suchthat}\{s = |X(f) - \langle X(f) \rangle | | s \le t\} = n)$$

$$\langle Y(f) \rangle = \sum_{i=0}^{n} Y^{(i)}(f)$$

This is how we implemented it with python. If you wanna checkout whole code then it is in the appendix.

Also, as discussed from the previous section we have to correct these terms with ENBW. Time constant (T)= 100 and roll-off =12 dB/oct

$$ENBW = \frac{1}{8T} = 1250Hz$$

With all this in we got following results,

Here we can see some traces of flicker noise. Parameterized as follows,

$$S_{flicker}(f) = 5.90923491 \frac{1}{f^{1.34677368}}$$
$$S_{white}(f) = 2.0644381e - 05$$

4.2 Very low frequency: upto 1 hertz

Let's take a second data set where we have sub hertz frequency data. This data set have each frequency with corresponding 50 values. Raw data looks like figure 11.

For analysing data ENBW is calculated for TIME CONSTANT = 100ms and roll of factor 12db/oct,

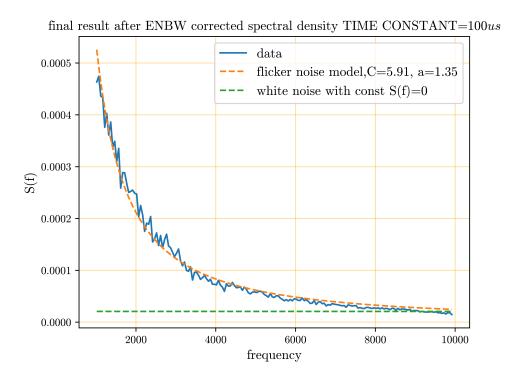


Figure 10: final analysed data for 1k to 10k hertz frequency with TIME CONSTANT = $100\mu s$ and 12db/oct

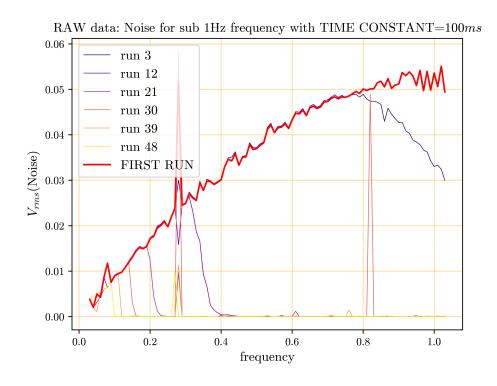


Figure 11: This is row data for sub one hertz band with TIME CONSTANT = 100ms and roll of factor 12db/oct

$$ENBW = \frac{1}{8T} = 1.25Hz$$

Final data will be look like this,

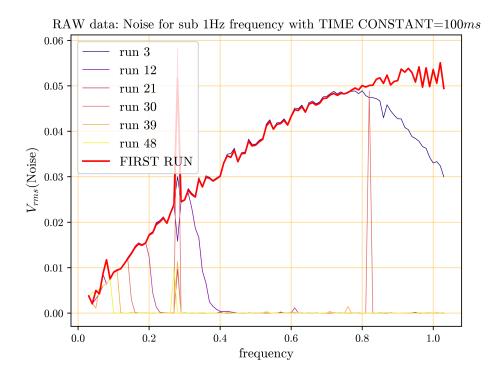


Figure 12: final analysed data for sub one hertz band with TIME CONSTANT = 100ms and roll of factor 12db/oct

Appendix

Code for data analysis

This is code for where I made my tools for data analysis. This tools presents with me file opening, file reading, taking mean over single frequency data, sorting my data with deviation method, plotting single data points form points etc.

```
import csv
import re
from numpy import array, mean, abs, split, vstack, argsort, column_stack
__all__=[
   "files"
class files:
   PARAMETER: filename as Relative path to __file__
   RETURN: nil
   FUNCTION: read files named filename, write other files with data
   def __init__(self,filename:str,datatype=float) -> None:
        self.datatype = datatype
        self.filename = filename
       with open(filename, 'r',) as newfile:
            self.fobject = list(csv.reader(newfile))
            # omit first member
            try:
                datatype(self.fobject[0][0])
                self.header = None
            except ValueError:
                self.header = self.fobject.pop(0)
            self.length = sum(1 for row in self.fobject)
   def file_add(self,nameaddition:str="extra"):
        _finalfile = re.split("\/",self.filename)
        finalfile = re.split("\.", _finalfile[len(_finalfile)-1])
        self.finalfile = "/".join(str(_finalfile[i]) for i in range(len(_finalfile)-1))
   def write_another(self,data:list)-> None:
        with open(self.finalfile, 'wxs', newline="") as cleandata:
            writer = csv.writer(cleandata)
            writer.writerow(data)
```

```
def get_mean(self):
    data = array(self.fobject)
    try:
        first_array,second_array = split(data,2,axis=1)
    except IndexError:
        print("from get_mean()::empty array from data")
    extra_array,_first_array,_second_array = [],[],[]
    count = 0
    _first_array.append(first_array[count][0])
    for i in range(0,len(data)):
        if first_array[i][0] == first_array[count]:
            extra array.append(second array[i][0])
        else:
            _second_array.append(mean(array(extra_array,dtype=float)))
            _first_array.append(first_array[i][0])
            extra array=[]
        if i==len(first_array)-1:
            _second_array.append(mean(array(extra_array,dtype=float)))
    return vstack((array(_first_array,dtype=float),array(_second_array,dtype=float)
def sort_on_deviation(self, points=5):
    data = array(self.fobject, dtype=float)
    filtered_data=[]
    temp_erray = []
    index = float(data[0][0])
    count = 0
    for datapoint in data:
        count+=1
        if datapoint[0] == index:
            temp_erray.append(float(datapoint[1]))
        else:
            nlist = array(temp_erray,dtype=float)
            m = mean(nlist)
            sorted_deviation = argsort(abs(nlist - m))
            filtered_nlist = nlist[sorted_deviation[:points]]
            indexonelist = array([index]*points)
            final_list= column_stack((indexonelist,filtered_nlist))
            for member in final_list:
                filtered_data.append(member)
            index = float(datapoint[0])
            temp_erray = []
        if count == len(data)-1:
```

```
nlist = array(temp_erray,dtype=float)
            m = mean(nlist)
            sorted_deviation = argsort(abs(nlist - m))
            filtered_nlist = nlist[sorted_deviation[:points]]
            indexonelist = array([index]*points)
            final_list= column_stack((indexonelist,filtered_nlist))
            for member in final_list:
                filtered data.append(member)
    return array(filtered_data)
def shady plot(self, color="Blues"):
    11 11 11
    data = array(self.fobject,dtype=float)
    # [here] can be better memort handling !
    common_array = [[]]
    index = float(data[0][0])
    count = 0
    for datapoint in data:
        if float(datapoint[0]) == index:
            try:
                common_array[count].append([float(datapoint[0]),float(datapoint[1])
                count+=1
            except IndexError:
                common_array.append([])
                common_array[count].append([float(datapoint[0]),float(datapoint[1])
                count+=1
        else:
            count=0
            index = float(datapoint[0])
    delete = []
    common_array.pop()
    for i in range(len(common_array)-1):
        if len(common_array[len(common_array)-1])<len(common_array[i]):</pre>
            common_array[i].pop()
    common_array = array(common_array)
    from matplotlib import cm
    colormap = cm.get_cmap(color, len(common_array))
    return common_array,colormap
def point_mean(self,data):
    freq = []
    vo = []
    freq.append(float(data[0][0]))
    vo.append(float(data[0][1]))
```

```
count = 1
for i in range(1,len(data)):
    lenth = len(freq)
    if float(data[i][0]) == freq[lenth-1]:
        vo[lenth-1] += float(data[i][1])
        count += 1
    else:
        vo[lenth-1] = vo[lenth-1] / count
        count = 1
        freq.append(float(data[i][0]))
        vo.append(float(data[i][1]))
    freq.pop()
    vo.pop()
    return array(freq,dtype=float),array(vo,dtype=float)

if __name__ == "__main__":
    print("No Error")
```

References